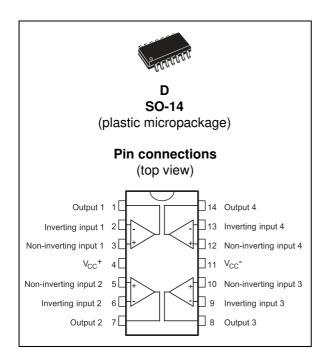


Precision quad operational amplifier

Datasheet - production data



Description

The TS514 device is a high-performance quad operational amplifier with frequency and phase compensation built into the chip. The internal phase compensation allows stable operation as a voltage follower in spite of its high gain bandwidth.

The circuit presents very stable electrical characteristics over the entire supply voltage range, and is particularly intended for professional and telecom applications (such as active filters, for example).

Features

- Low input offset voltage: 500 μV max.
- Low power consumption
- Short-circuit protection
- Low distortion, low noise
- High gain bandwidth product
- High channel separation
- ESD protection 2 kV

Contents TS514

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1 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	±18	V
V _i	Input voltage	V _{DD} -0.2 to V _{CC} +0.2	V
V _{id} ⁽¹⁾	Differential input voltage	±V _{CC}	V
T _{stg}	Storage temperature range	-65 to +150	°C
R _{thja}	Thermal resistance junction-to-ambient SO-14	103	°C/W
R _{thjc}	Thermal resistance junction-to-case SO-14	31	°C/W
	HBM: human body model ⁽²⁾	2	kV
ESD	MM: machine model ⁽³⁾	200	V
	CDM: charged device model ⁽⁴⁾	1.5	kV

- 1. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
- 3. Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.
- 4. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to ground through only one pin. This is done for all pins.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	6 to 30	V
V _{icm}	Common mode input voltage range	V_{DD} +0.8 to V_{CC} -1.5	٧
T _{oper}	Operating free air temperature range	-40 to +125	°C



Schematic diagram TS514

2 Schematic diagram

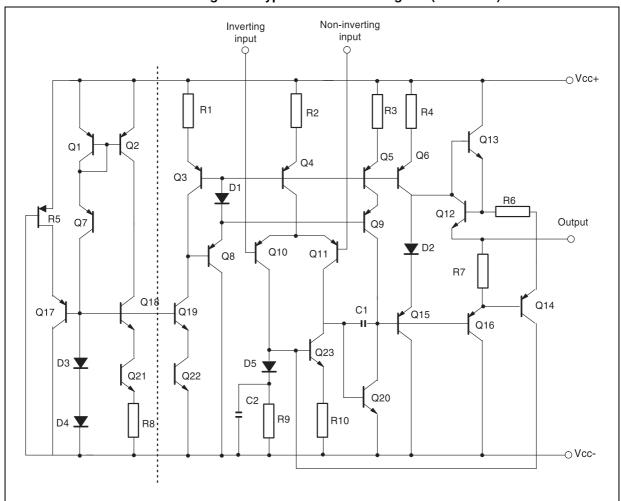


Figure 1. Typical schematic diagram (1/4 TS514)

3 Electrical characteristics

Table 3. Electrical characteristics at V_{CC} = ±15 V, T_{amb} = 25 °C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit
I _{CC}	Supply current (per operator) at $T_{min} \le T_{op} \le T_{max}$		0.5	0.6 0.75	mA
l _{ib}	Input bias current — at 25 °C — at $T_{min} \le T_{op} \le T_{max}$		50	150 300	nA
R _i	Input resistance, F= 1 kHz		1		$M\Omega$
V _{io}	Input offset voltage $- \text{ at } 25 ^{\circ}\text{C}$ $TS514$ $TS514A$ $- \text{ at } T_{\text{min}} \leq T_{\text{op}} \leq T_{\text{max}}$ $TS514$ $TS514$		0.5	2.5 0.5 4 1.5	mV
ΔV_{io}	Input offset voltage drift at $T_{min} \le T_{op} \le T_{max}$		5		μV/°C
I _{io}	Input offset current at 25 °C at $T_{min} \le T_{op} \le T_{max}$		5	20 40	nA
Δl_{io}	Input offset current drift $T_{min} \le T_{op} \le T_{max}$		0.08		<u>nA</u> ∘C
I _{os}	Output short-circuit current		23		mA
A _{vd}	Large signal voltage gain, $R_L = 2 \text{ k}\Omega$ $V_{CC} = \pm 15 \text{ V}$, at $T_{min} \leq T_{op} \leq T_{max}$ $V_{CC} = \pm 4 \text{ V}$	90	100 95		dB
GBP	Gain bandwidth product, F = 100 kHz	1.8	3		MHz
e _n	Equivalent input noise voltage, F = 1 kHz Rs = 50 Ω Rs = 1 k Ω Rs = 10 k Ω		8 10 18	15	<u>nV</u> √Hz
THD	Total harmonic distortion Av = 20 dB, $R_L = 2 k\Omega$, $V_o = 2 V_{pp}$, $f = 1 kHz$		0.03	0.1	%
±V _{opp}	Output voltage swing, $R_L = 2 \text{ k}\Omega$ $V_{CC} = \pm 15 \text{ V}$, at $T_{min} \leq T_{op} \leq T_{max}$ $V_{CC} = \pm 4 \text{ V}$	±13	±3		V
V _{opp}	Large signal voltage swing, $R_L = 2 \text{ k}\Omega$, $F = 10 \text{ kHz}$		28		V_{pp}
SR	Slew rate, unity gain, $R_L = 2 \text{ k}\Omega$	0.8	1.5		V/µs
CMR	Common mode rejection ratio CMR = 20 log $(\Delta V_{ic}/\Delta V_{io})$ $(V_{ic}$ = -10 V to 10 V, V_{out} = $V_{CC}/2$, R_L > 1 M Ω)	90			dB

Electrical characteristics TS514

Table 3. Electrical characteristics at V_{CC} = ±15 V, T_{amb} = 25 °C (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Тур.	Max.	Unit
	Supply voltage rejection ratio 20 log $(\Delta V_{CC}/\Delta V_{io})$ $(V_{CC}=\pm 5~V$ to $\pm 15~V$, $V_{out}=V_{icm}=V_{CC}/2)$	90			dB
V_{o1}/V_{o2}	Channel separation, F = 1 kHz		120		dB



TS514 Electrical characteristics

Figure 2. V_{io} distribution at V_{CC} = ±15 V and T = 25 °C

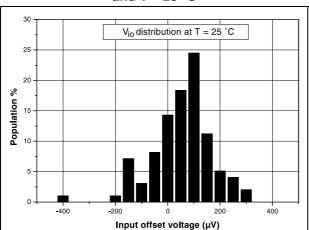


Figure 3. V_{io} distribution at V_{CC} = ±15 V and T = 125 °C

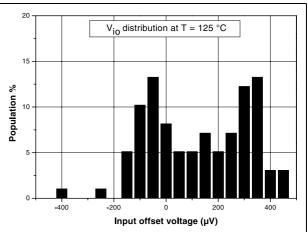
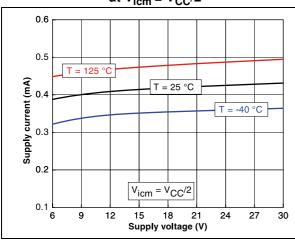


Figure 4. Input offset voltage vs. supply voltage Figure 5. Input offset voltage vs. input common at $V_{icm} = V_{CC}/2$ mode voltage at $V_{CC} = 6 \text{ V}$



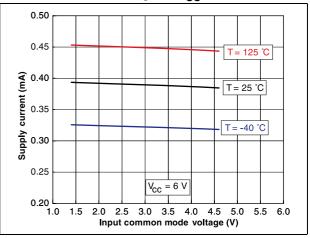
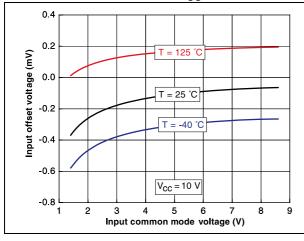
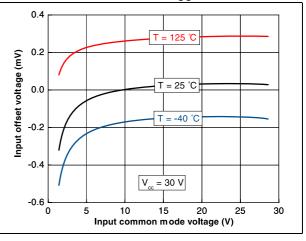


Figure 6. Input offset voltage vs. input common mode voltage at $V_{CC} = 10 \text{ V}$ mode voltage at $V_{CC} = 30 \text{ V}$

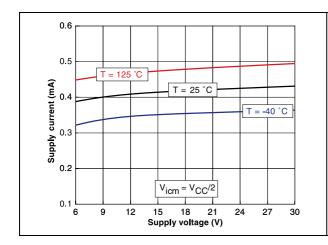




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Figure 8. Supply current (per operator) vs. supply voltage at V_{icm} = V_{CC}/2

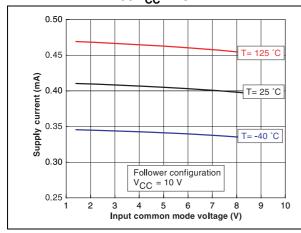
Figure 9. Supply current (per operator) vs. input common mode voltage at V_{CC} = 6 V



0.50 0.45 T = 125 °C T = 25 °C T = -40 °C T = -40 °C T = -40 °C 0.20 1.0 1.5 2.0 2.5 3.0 3.5 4.0 4.5 5.0 5.5 6.0 Input common mode voltage (V)

Figure 10. Supply current (per operator) vs. input common mode voltage at V_{CC} = 10 V

Figure 11. Supply current (per operator) vs. input common mode voltage at V_{CC} = 30 V



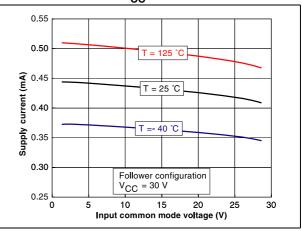
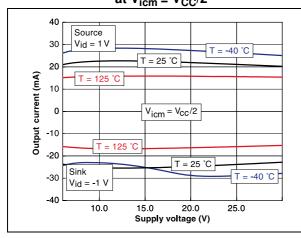
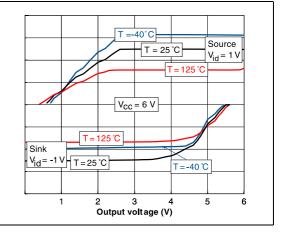


Figure 12. Output current vs. supply voltage at $V_{icm} = V_{CC}/2$

Figure 13. Output current vs. output voltage at $V_{CC} = 6 \text{ V}$





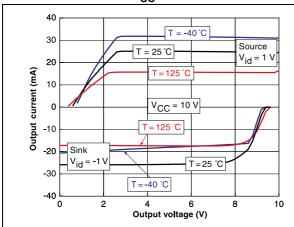


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TS514 Electrical characteristics

Figure 14. Output current vs. output voltage at $V_{CC} = 10 \text{ V}$

Figure 15. Output current vs. output voltage at $V_{CC} = 30 \text{ V}$



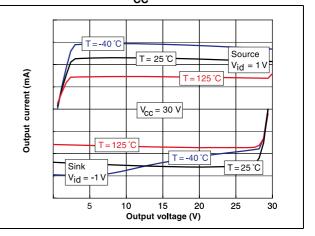
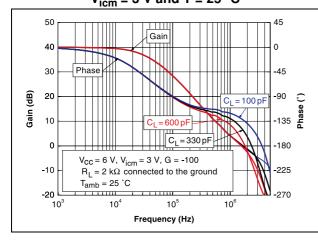


Figure 16. Voltage gain and phase for different Figure 17. Voltage gain and phase for different capacitive load at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

capacitive load at $V_{CC} = 10 \text{ V}$, V_{icm} = 5 V and T = 25 °C



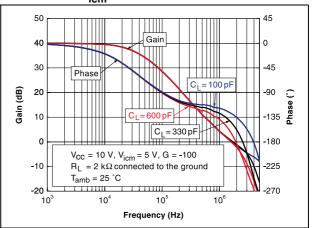
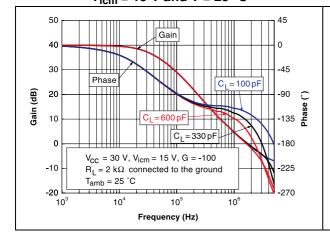
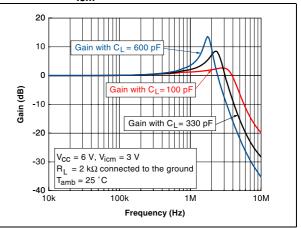


Figure 18. Voltage gain and phase for different capacitive load at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C

Figure 19. Frequency response for different capacitive load at $V_{CC} = 6 V$, $V_{icm} = 3 V \text{ and } T = 25 °C$

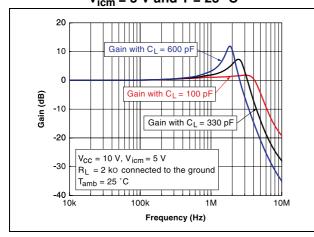




Electrical characteristics TS514

Figure 20. Frequency response for different capacitive load at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C

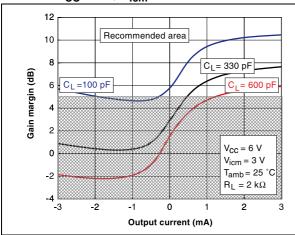
Figure 21. Frequency response for different capacitive load at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C



20 10 Gain with C_L = 600 pF 0 Gain with C_L = 100 pF -10 Gain with C_L= 330 pF -20 V_{CC} = 30 V, V_{icm} = 15 V R_L = 2 $k\Omega$ connected to the ground T_{amb} = 25 $^{\circ}C$ -40 10k 100k 1M 10M Frequency (Hz)

Figure 22. Gain margin vs. output current, at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

Figure 23. Gain margin vs. output current, at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C



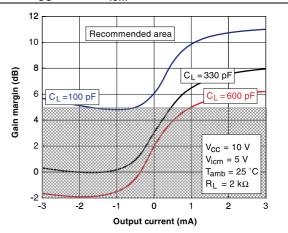
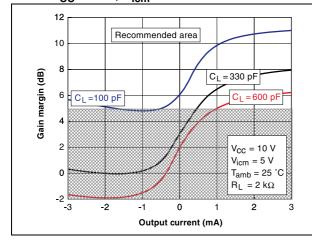
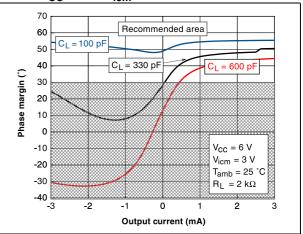


Figure 24. Gain margin vs. output current, at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C

Figure 25. Phase margin vs. output current, at V_{CC} = 6 V, V_{icm} = 3 V and T = 25 °C

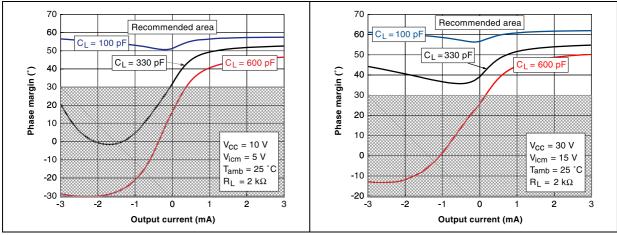




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Figure 26. Phase margin vs. output current, at V_{CC} = 10 V, V_{icm} = 5 V and T = 25 °C Figure 27. Phase margin vs. output current, at V_{CC} = 30 V, V_{icm} = 15 V and T = 25 °C

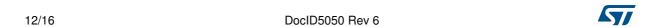




Package information TS514

4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



TS514 Package information

4.1 SO-14 package information

Figure 28. SO-14 package outline

Table 4. SO-14 package mechanical data

			Dimer	nsions		
Symbol	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	1.35		1.75	0.05		0.068
A1	0.10		0.25	0.004		0.009
A2	1.10		1.65	0.04		0.06
В	0.33		0.51	0.01		0.02
С	0.19		0.25	0.007		0.009
D	8.55		8.75	0.33		0.34
Е	3.80		4.0	0.15		0.15
е		1.27			0.05	
Н	5.80		6.20	0.22		0.24
h	0.25		0.50	0.009		0.02
L	0.40		1.27	0.015		0.05
k	8° (max.)					
ddd			0.10			0.004

D and F dimensions do not include mold flash or protrusions. Mold flash or protrusions must not exceed 0.15 mm.



Note:

Ordering information TS514

5 Ordering information

Table 5. Order codes

Order code	Temperature range	Package	Packaging	Marking
TS514ID TS514IDT	-40, + 125 °C	SO-14	Tube or	5141
TS514AID TS514AIDT	- 4 0, + 123	30-14	tape and reel	514AI

TS514 Revision history

6 Revision history

Table 6. Document revision history

Date	Revision	Changes
09-Mar-2001	1	Initial release.
23-Jun-2005	2	Automotive grade part references inserted in the datasheet (see Chapter 5: Ordering information on page 14).
30-Sep-2005	3	 The following changes were made in this revision. An error in the device description was corrected on page 1. Chapter 5: Ordering information on page 14 updated with complete list of markings. Addition of supplementary data in Table 1: Absolute maximum ratings on page 2. Addition of Table 2: Operating conditions on page 2. Reorganization of Chapter 4: Package information on page 11. Minor grammatical and formatting changes throughout.
24-Oct-2008	4	Added performance AC and DC characteristic curves for VCC=6 V, VCC=10 V and VCC=30 V in Chapter 3: Electrical characteristics. Modified ICC typ, added parameters over temperature in Table 3. Deleted old macromodel. Added Rthjc, Rthja in Table 1. Corrected Vi and Vid AMR values in Table 1. Added input common mode range Vicm in Table 2: Operating conditions. Updated Section 4.1: DIP14 package information and Section 4.2: SO-14 package information
12-Sep-2012 5		Updated Features (removed "macromodel"). Updated CMR and SVR test conditions in Table 3. Updated ECOPACK text in Section 4. Removed TS514IYD, TS514IYDT, TS514AIYD, and TS514AIYDT order code from Table 6. Minor corrections throughout document.
07-Nov-2024	6	Removed obsolete part numbers. Updated <i>Table 5</i> .

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